

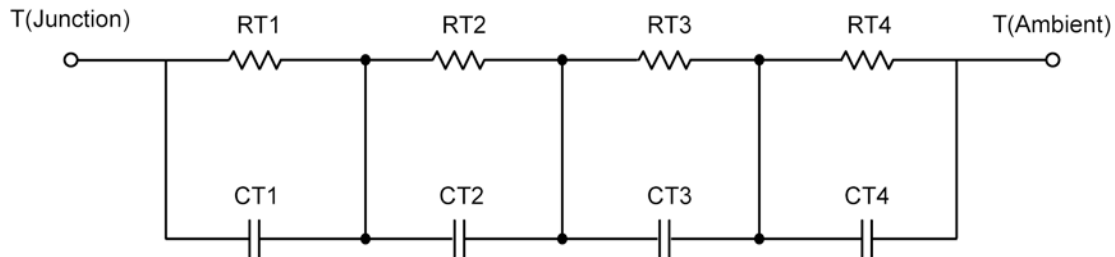
## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

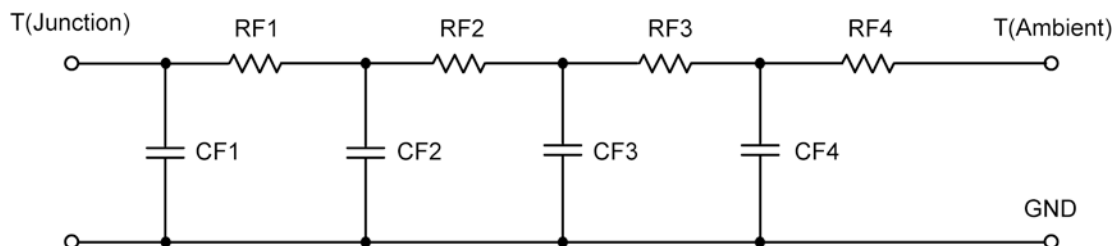
These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	1.6621	2.6142 m	N/A
RT2	10.8283	79.5977 m	N/A
RT3	9.6105	1.2909	N/A
RT4	42.8991	426.8881 m	N/A
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	11.3885 m	260.0671 u	N/A
CT2	1.0702	65.2811 u	N/A
CT3	68.0021 m	11.7843 m	N/A
CT4	1.7459	10.1327 m	N/A

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**

<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ )			
Junction to	Ambient	Case	Foot
RF1	2.9048	93.0663 m	N/A
RF2	11.2283	1.0569	N/A
RF3	20.3146	646.9451 m	N/A
RF4	30.5523	3.0886 m	N/A
Thermal Capacitance (Joules/ $^{\circ}\text{C}$ )			
Junction to	Ambient	Case	Foot
CF1	18.0920 m	539.8341 u	N/A
CF2	52.8432 m	4.6571 m	N/A
CF3	633.8348 m	14.1488 m	N/A
CF4	1.5002	289.4735 m	N/A

**Note**

NA indicates not applicable

